

L Number	Hits	Search Text	DB	Time stamp
-	1	5976976.pn.	USPAT; JPO	2002/01/31 09:02
-	1	6031288.pn.	USPAT; JPO	2002/01/29 15:45
-	135	438/\$.ccls. and zinc same titani\$3 and silicon and tungsten	USPAT; JPO	2002/01/30 13:50
-	122	(438/\$.ccls. and zinc same titani\$3 and silicon and tungsten) and nitr\$5	USPAT; JPO	2002/01/29 15:48
-	83	((438/\$.ccls. and zinc same titani\$3 and silicon and tungsten) and nitr\$5) and alloy	USPAT; JPO	2002/01/29 15:48
-	65	438/\$.ccls. and zinc same titani\$3 same alloy and silicon and tungsten	USPAT; JPO	2002/01/29 15:49
-	25	438/\$.ccls. and zinc same titani\$3 same alloy and titani\$ with silicide and tungsten	USPAT; JPO	2002/01/29 15:50
-	17	(438/\$.ccls. and zinc same titani\$3 same alloy and titani\$ with silicide and tungsten) and bpsg	USPAT; JPO	2002/01/29 15:50
-	21	(438/\$.ccls. and zinc same titani\$3 same alloy and titani\$ with silicide and tungsten) and silic\$3 with \$2oxide	USPAT; JPO	2002/01/29 15:51
-	14	(438/\$.ccls. and zinc same titani\$3 same alloy and titani\$ with silicide and tungsten) and silic\$3 with \$2oxide and bpsg	USPAT; JPO	2002/01/29 16:17
-	1	4884123.pn.	USPAT; JPO	2002/01/29 16:17
-	1	5232873.pn.	USPAT; JPO	2002/01/30 10:13
-	1	4343870.pn.	USPAT; JPO	2002/01/30 09:28
-	1	5232873.pn. and titanium same zinc	USPAT; JPO	2002/01/30 10:14
-	4	438/\$.ccls. and seed same zinc same titani\$3	USPAT; JPO	2002/01/30 10:42
-	16	438/\$.ccls. and cvd same zinc and titani\$3 and tungsten and semiconductor	USPAT; JPO	2002/01/30 13:41
-	139	438/\$.ccls. and zinc same titani\$3 and tungsten	USPAT; JPO	2002/01/30 13:51
-	37	438/\$.ccls. and zinc same titani\$3 and tungsten and bpsg	USPAT; JPO	2002/01/30 14:10
-	1	4751101.pn.	USPAT; JPO	2002/01/30 14:16
-	1	4343870.pn.	USPAT; JPO	2002/01/30 14:30
-	5	438/\$.ccls. and zinc with (dialkyl or trimethyl) and titani\$4 and hydrogen	USPAT; JPO	2002/01/30 15:00
-	1	5173327.pn.	USPAT; JPO	2002/01/30 15:11
-	1	5828131.pn.	USPAT; JPO	2002/01/30 15:39
-	0	437/\$.ccls. and 438/\$.ccls. and titanium adj alloy same zinc and contact	USPAT; JPO	2002/01/30 15:41
-	0	437/\$.ccls. and 438/\$.ccls. and titanium adj alloy same zinc	USPAT; JPO	2002/01/30 15:41
-	10	438/\$.ccls. and titanium adj alloy same zinc	USPAT; JPO	2002/01/30 15:45
-	23	semiconductor and titanium adj alloy same zinc	USPAT; JPO	2002/01/30 15:53
-	15	semiconductor and titanium adj alloy with zinc	USPAT; JPO	2002/01/30 15:54
-	264	sputter same titanium same argon and semiconductor	USPAT; JPO	2002/01/31 09:03
-	0	sputter same titanium same argon same zinc and semiconductor	USPAT; JPO	2002/01/31 09:04
-	7	sputter same titanium same argon and semiconductor and zinc	USPAT; JPO	2002/01/31 09:16

-	0	sputter same zinc same titanium same argon and semiconductor and zinc	USPAT; JPO	2002/01/31 09:08
-	9	titanium adj alloy same zinc and (semiconductor.ab.)	USPAT; JPO	2002/01/31 09:29
-	92	titanium adj alloy same (aluminum or tin or gallium) and titanium same tungsten and (semiconductor.ab.)	USPAT; JPO	2002/01/31 09:30
-	86	titanium adj alloy same aluminum and titanium same tungsten and (semiconductor.ab.)	USPAT; JPO	2002/01/31 09:30
-	80	titanium adj alloy with aluminum and titanium same tungsten and (semiconductor.ab.)	USPAT; JPO	2002/01/31 09:32
-	71	titanium adj alloy with aluminum and titanium same tungsten and contact and (semiconductor.ab.)	USPAT; JPO	2002/01/31 09:32
-	24	titanium adj alloy with aluminum and titanium same tungsten and titanium same silicide and contact and (semiconductor.ab.)	USPAT; JPO	2002/01/31 09:52
-	9	cvd same titanium same zinc and (semiconductor.ab.)	USPAT; JPO	2002/01/31 10:56
-	6	cvd same titanium with zinc and (semiconductor.ab.)	USPAT; JPO	2002/01/31 11:09
-	63	cvd same titanium with zinc	USPAT; JPO	2002/01/31 11:10
-	16	cvd with titanium with zinc	USPAT; JPO	2002/01/31 11:10
-	0	cvd with titanium with zinc and superconductor	USPAT; JPO	2002/01/31 11:10
-	16	cvd with titanium with zinc	USPAT; JPO	2002/01/31 11:12
-	8	cvd with titanium with zinc and semiconductor	USPAT; JPO	2002/01/31 11:15
-	1	cvd with titanium with zinc and integrated adj circuit	USPAT; JPO	2002/01/31 11:37
-	1	5489548.pn.	USPAT; JPO	2002/01/31 13:39
-	519	integrated with circuit and titanium with zinc	USPAT; JPO	2002/01/31 13:50
-	47	(integrated with circuit and titanium with zinc) and titanium with silicide	USPAT; JPO	2002/01/31 13:45
-	1636	integrated with circuit and titanium with silicon and titanium with silicide and (tungsten or aluminum)	USPAT; JPO	2002/01/31 13:56
-	1437	integrated with circuit and titanium with silicon and titanium with silicide and tungsten	USPAT; JPO	2002/01/31 13:58
-	1314	integrated with circuit and titanium with silicon and titanium with silicide and tungsten and contact	USPAT; JPO	2002/01/31 14:00
-	1263	integrated with circuit and titanium with silicon and titanium with silicide and tungsten and contact and semiconductor	USPAT; JPO	2002/01/31 14:01
-	644	integrated with circuit and titanium with silicon and titanium with silicide and tungsten and contact and semiconductor and via	USPAT; JPO	2002/01/31 14:03
-	56	integrated with circuit and titanium with silicon and titanium with silicide and tungsten and contact and semiconductor and zinc	USPAT; JPO	2002/01/31 14:03